Thermionic Bunched Electron Sources for High-Energy Electron Cooling

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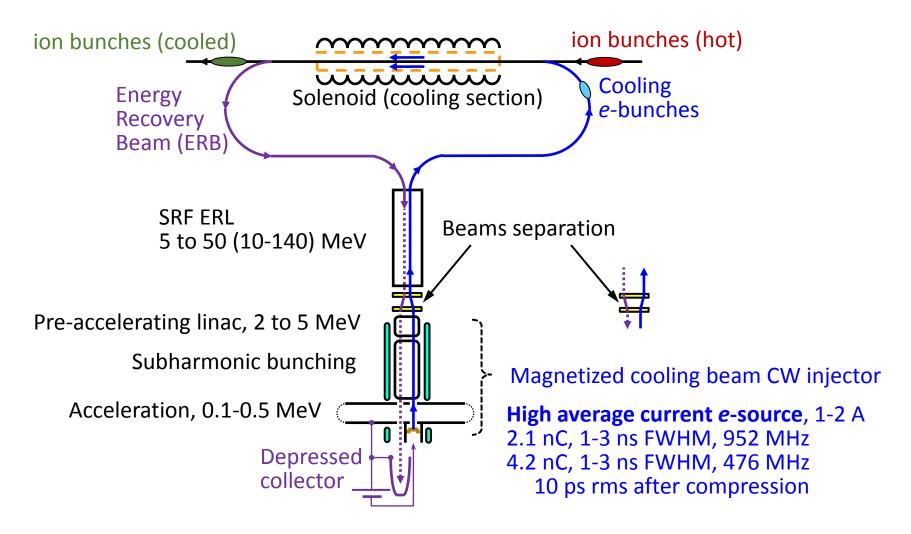
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Outline

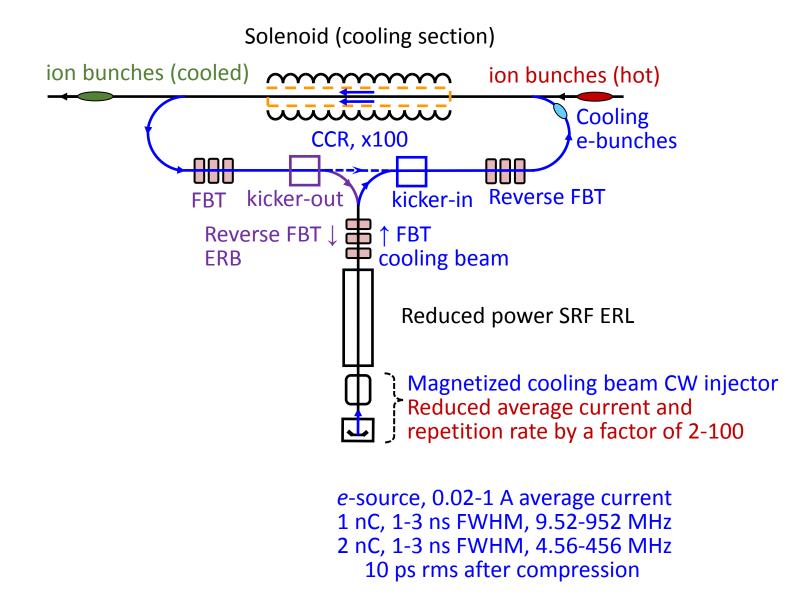
- HEEC schemes (e-sources, beam-beam kicker integration)
- Beam-beam kicker
- Required electron sources
- Emission gating and acceleration schemes
- Obtaining broad range of bunch repetition rates
- Summary

Single Current HEEC with Counter ERL



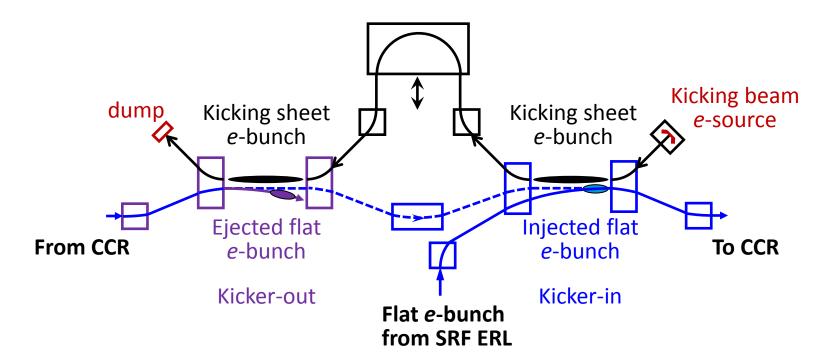
Y. Derbenev "Cooling with Magnetized Electron Beam" <u>MEIC Spring 2015</u>
 Y. Derbenev "Head-on ERL for HEEC" <u>JLEIC R&D Meeting</u>, CASA, March 17, 2016

Circulating Current HEEC with Counter ERL



Circulating Current HEEC

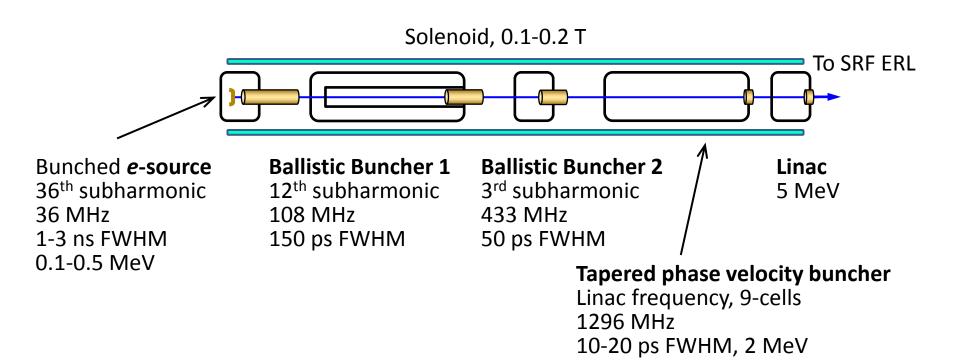
Beam-Beam Kicker with Magnet Dipoles



Kicking beam *e*-source

Bunched sheet beam, ~10x150 mm >2 nC, <1ns FWHM, 4.56-456 MHz >1 A average current, 0.1-0.5 MeV

Bunch Compression and Pre-acceleration



The scheme and example values adopted from

- 1. Yeremian *et al.* "Boeing 120 MeV RF linac injector design and accelerator performance comparison with PARMELA" <u>*Proc. PAC'89* IEEE (1989)</u>
- 2. C. H. Kim "Electron Injector Studies at LBL" *LBNL Paper* LBL-29227 (2010)
- 3. N. S. Sereno "Booster Subharmonic RF Capture Design" APS ANL, LS-297 (2002)

Required Electron Source Emission Gating and Acceleration

Gating Pulsed [1] Limitations

Limited repetition rate to low subharmonics Jitter errors (gap voltage, current, bunch charge, timing) Poor to no control HOM Limited grid voltage, 200 V (small gap, dense grid, higher emittance) Limited DC floating, 100 kV

$$I_{gap} \sim \frac{C_{gap} + C_{circuit}}{\tau_{rise}} \left(\frac{j_{peak} d_{gap}^2}{2.33 \cdot 10^{-6}}\right)^{2/3}$$

$$d_{\text{gap}} = 0.25 \text{ mm}, j_{\text{peak}} = 11 \text{A/cm}^2 \rightarrow U_{\text{gap}} = 200 \text{ V}$$

 $C_{\text{gap}}^+ C_{\text{circuit}} = 30 \text{ pF}, t_{\text{rise}} = 0.3 \text{ ns} \rightarrow I_{\text{gap}} = 20 \text{ A}$
 $C_{\text{circuit}} \text{ co-sources jitter.} \quad j_{\text{peak}} \text{ and } d_{\text{gap}} \text{ limit } I_{\text{gap}}$

1. M. J. Browne *et al.* "A multi-channel pulser for the SLC thermionic electron source" *PAC'85* <u>SLAC-PUB-3546.</u>

RF harmonicsRepetition rate from the linac frequency to its low subharmonicsAdvantagesNo jitter sourcesDC floating, 500 kVDC floating, 500 kVFor two and more harmonics, higher grid voltage, >200 V attainable
(larger gap, less dense grid, lower emittance)

Required Electron Source

Emission Gating and Acceleration

Acceleration

DC

10 MV/m (up to 30 MV/m with Mo) possible, CW (advantage) Applicable to long bunches, no RF curvature (advantage) HV DC insulation, Floating cathode (limitation) Limited to 0.5 MeV (limitation)

RF TM_{010} , $\lambda/4$ no HV DC insulation (advantage)Higher energies > 0.5 MeV in Linacs attainable (advantage)Limited accelerating gradient, <7 MV/m CW (limitation)</td>Due to larger TM_{010} cavity, bunch duration to be <0.3 ns FWHM (limit.)</td> $\lambda/4$ structures can work with longer bunches, <100 ns FWHM (advan.)</td>

Cooling beam CW *e*-source

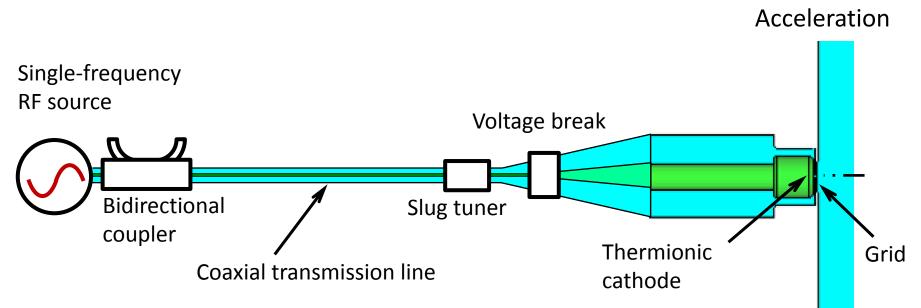
Bunched magnetized beam, ~3 mm radius 0.02-2 A average current 2.1 nC, 1-3 ns FWHM, 9.52-952 MHz 4.2 nC, 1-3 ns FWHM, 4.56-456 MHz 10 ps rms after compression

Kicking beam CW *e*-source

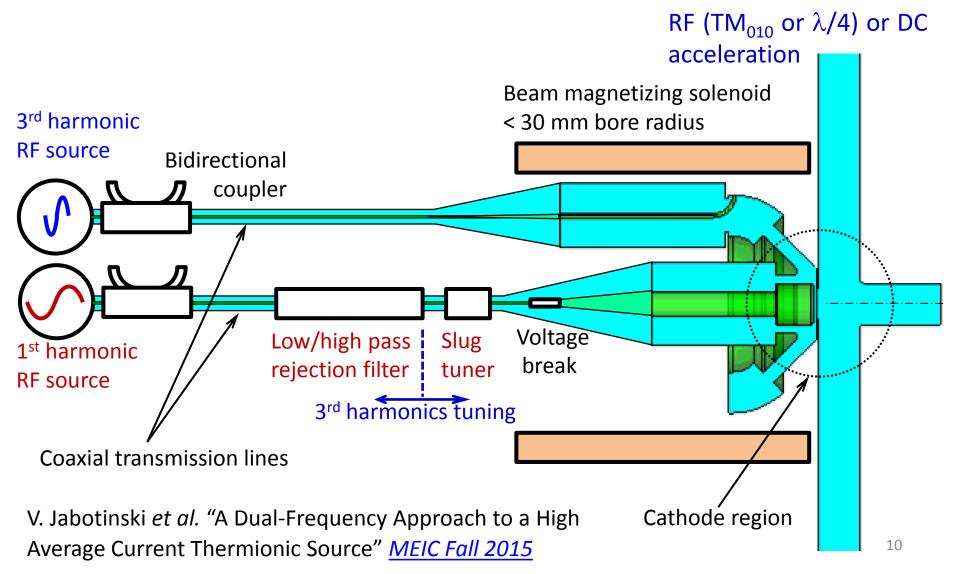
Bunched sheet beam, ~10x150 mm >1 A average current, 0.1-0.5 MeV >2 nC, <1ns гwнм, 4.56-456 MHz **Bunched electron sources. Gating and acceleration**

Single frequency gating of thermionic emission

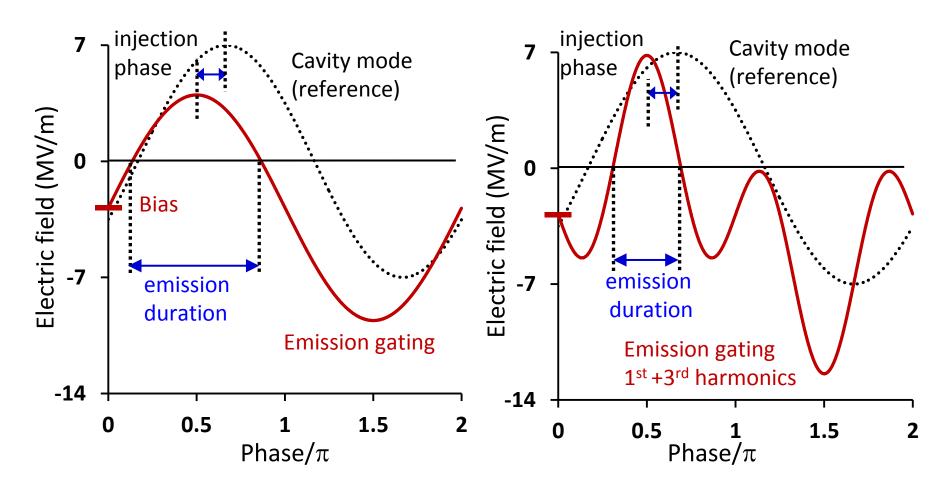
Gridded Cathode DC (IOTs, TRIUMF) or RF (TM₀₁₀ or $\lambda/4$) Acceleration Drawback: long bunch duration (slide 12)



Dual-Frequency Gating of Thermionic Emission 1st and $(2n+1)\lambda/4$ -modes 3rd-harmonic



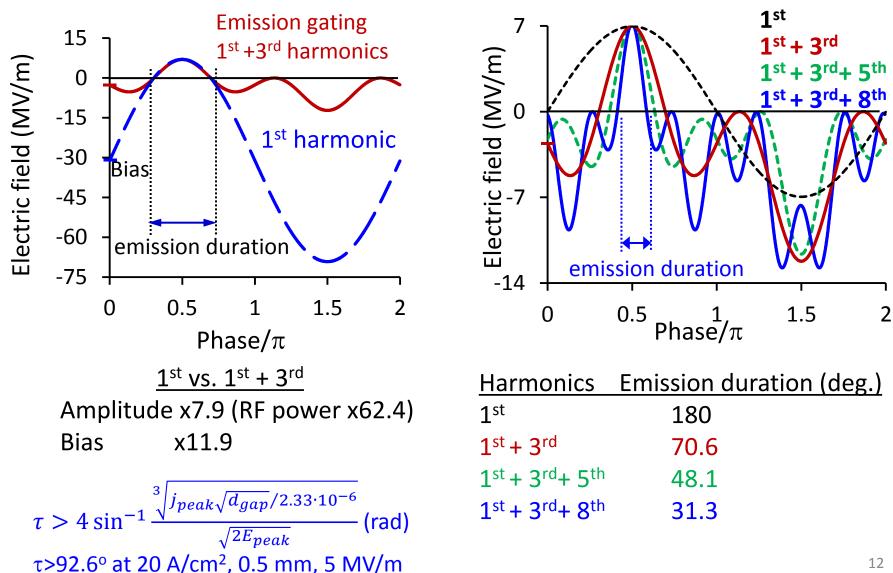
Dual-Frequency Gating of Thermionic Emission Shortening Bunch Duration



Gating the emission with the 1st harmonic (IOT, TRIUMF)

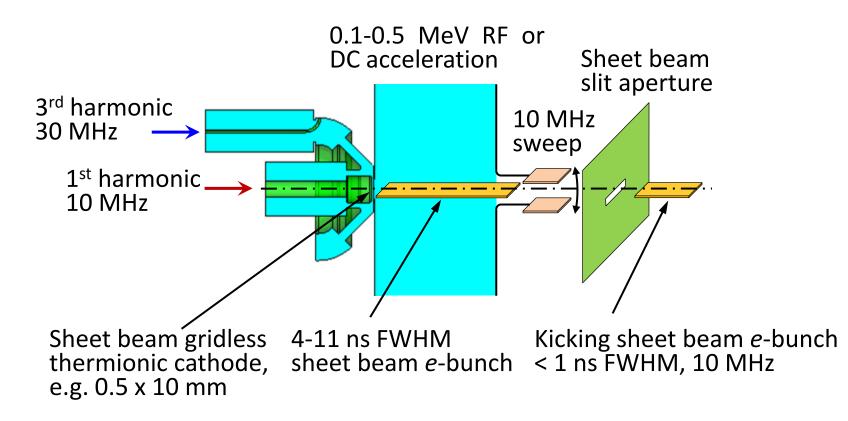
Gating the emission with the 1st and 3rd harmonics.

RF Gating of the Emission Effect of higher harmonics

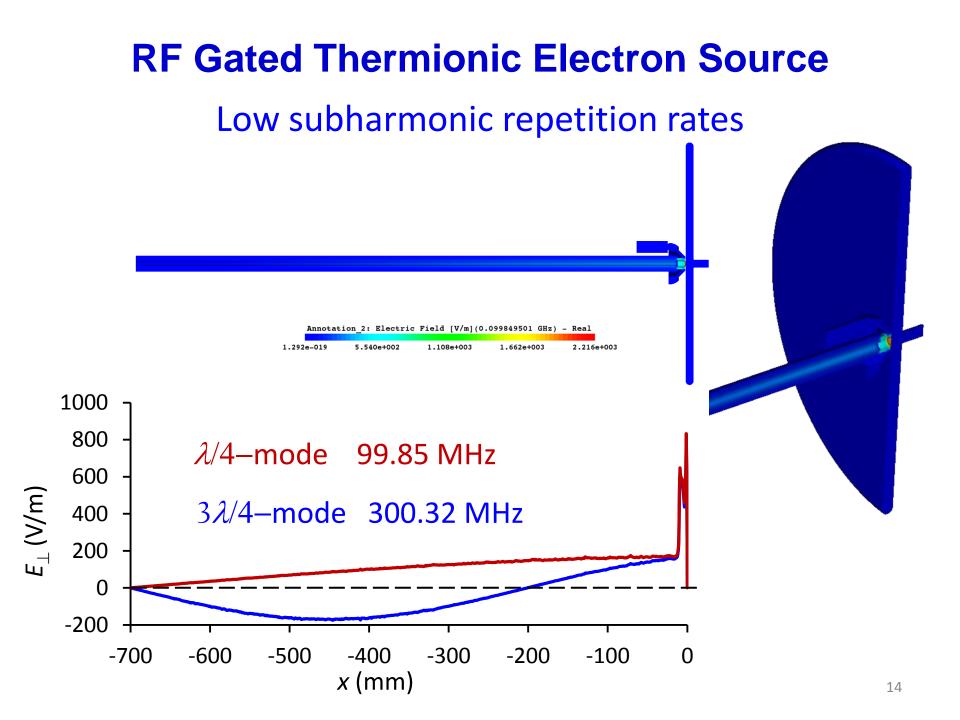


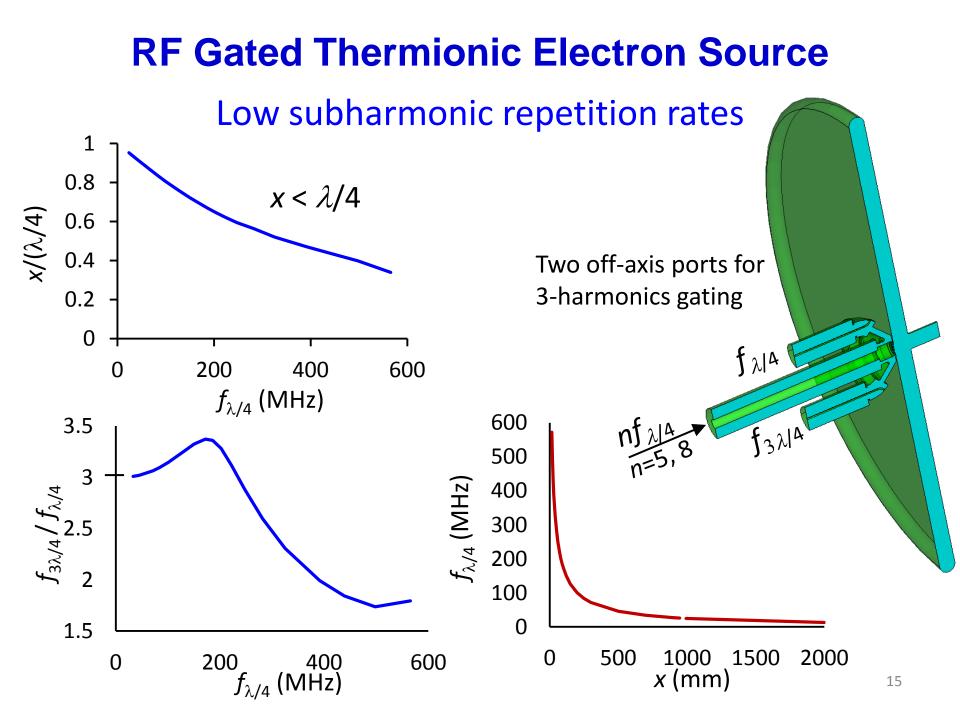
Kicking Sheet Beam E-source

Low subharmonic repetition rate



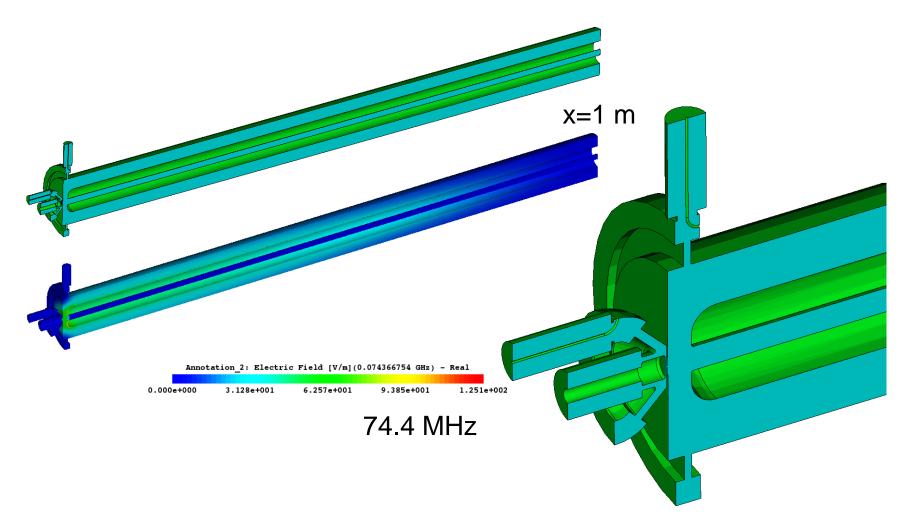
Sweeping is not needed for >40 MHz repetition rates or can be avoided with 3-harmonics gating for the lower frequencies, 10 MHz.





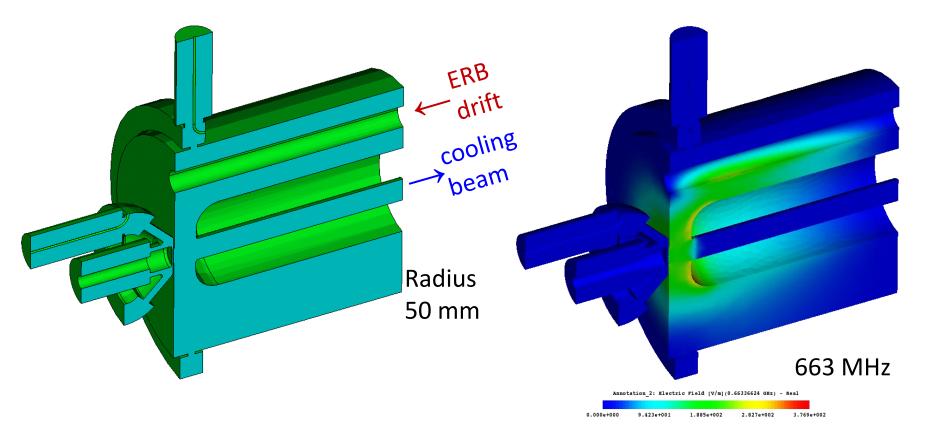
RF Gated Thermionic Electron Source

Quarter-wave bunching structure



RF Gated Thermionic Electron Source

Quarter-wave bunching structure with ERB drift tube

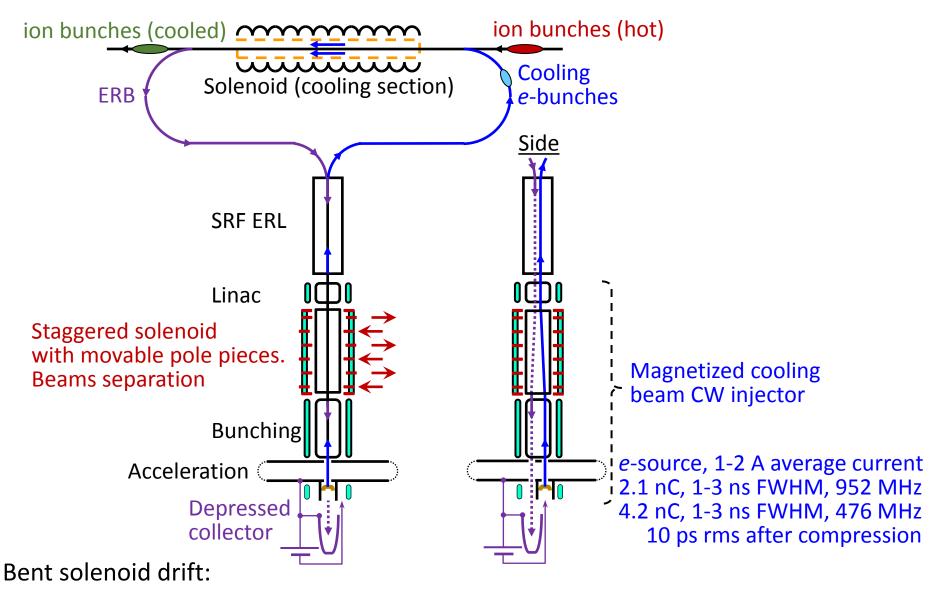


Summary

- We have considered HEEC schemes, identified critical components, their integration, and requirements including the needed electron sources and beam-beam kicker.
- Beam-beam kicker scheme using magnet dipoles is proposed
- Thermionic emission is inherently suitable for attaining high average current electron beams that are imperative for HEEC
- Methods for the emission gating and acceleration have been preliminary explored and e-sources for the cooling and the kicking beams are presented.
- Techniques aimed at low subharmonic repetition rates along with the linac frequency from the thermionic e-sources are discussed.
- Preliminary studies outlined the most critical approaches important to developing highly efficient HEEC and the electron sources.

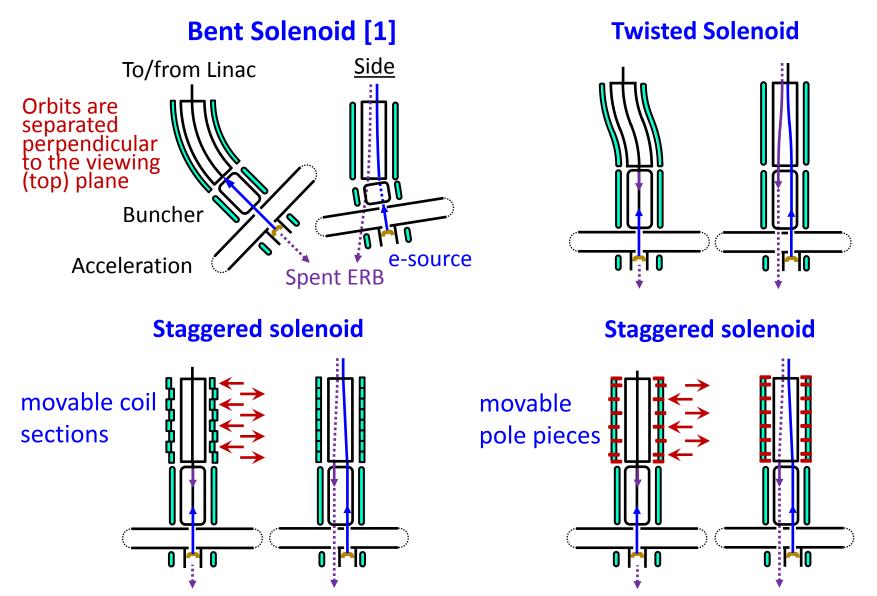
Back up slides

Counter ERL. In-Solenoid Beams Separation



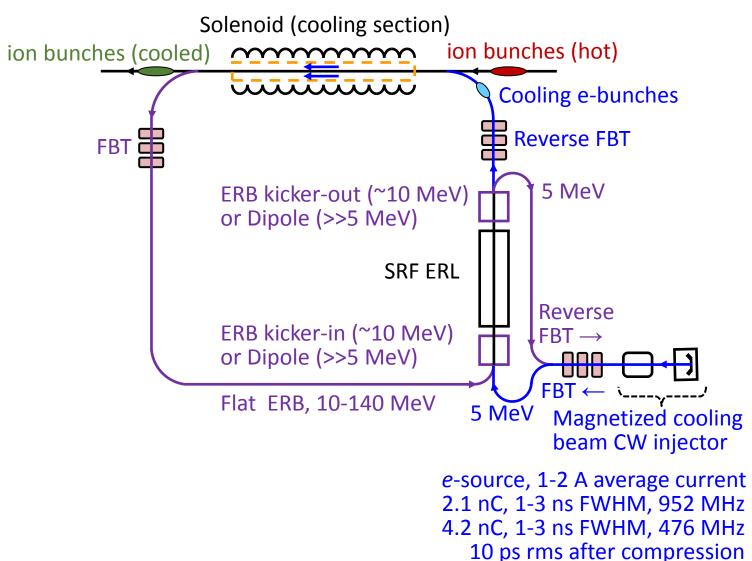
Y. Derbenev "Head-on ERL for HEEC" JLEIC R&D Meeting, CASA, March 17, 2016²⁰

Beams Separation using Bent Solenoid Drift



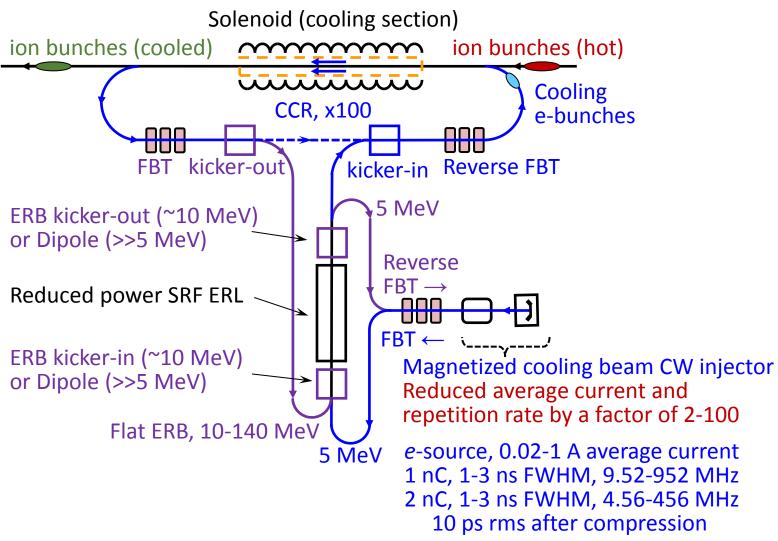
<u>1. Y. Derbenev "Head-on ERL for HEEC" JLEIC R&D Meeting, CASA, March 17, 2016</u>

Single Current HEEC Concurrent SRF ERL. Counter Injector Linac



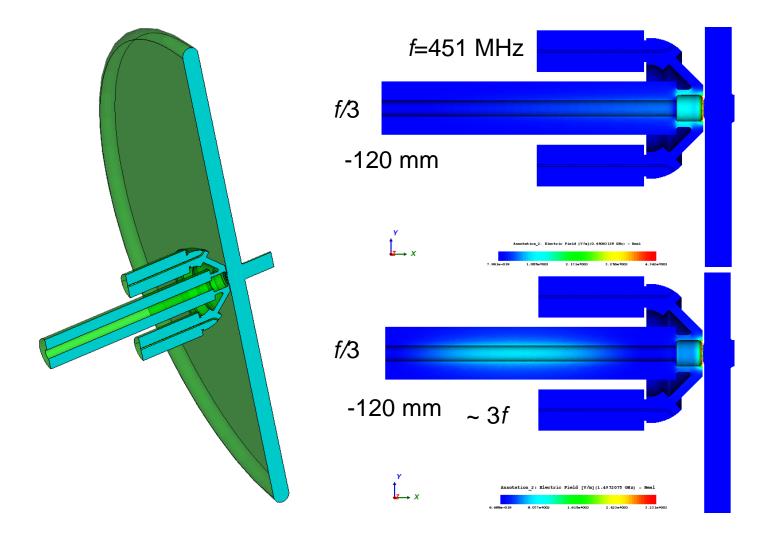
Circulating Current HEEC

Concurrent SRF ERL. Counter Injector Linac

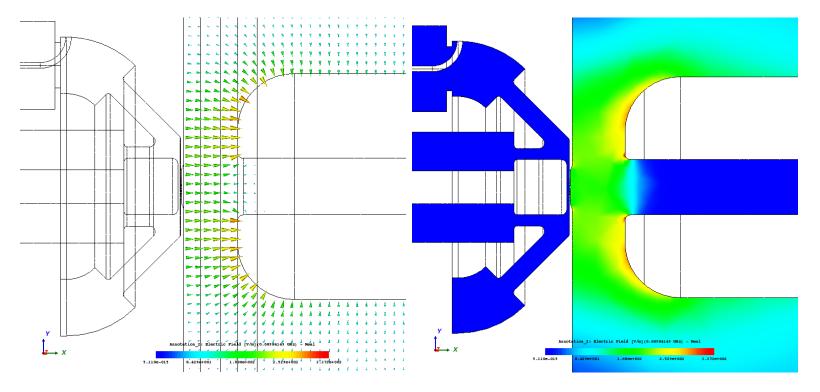


RF Gated Thermionic Electron Source

Two off axis ports for three-harmonics gating



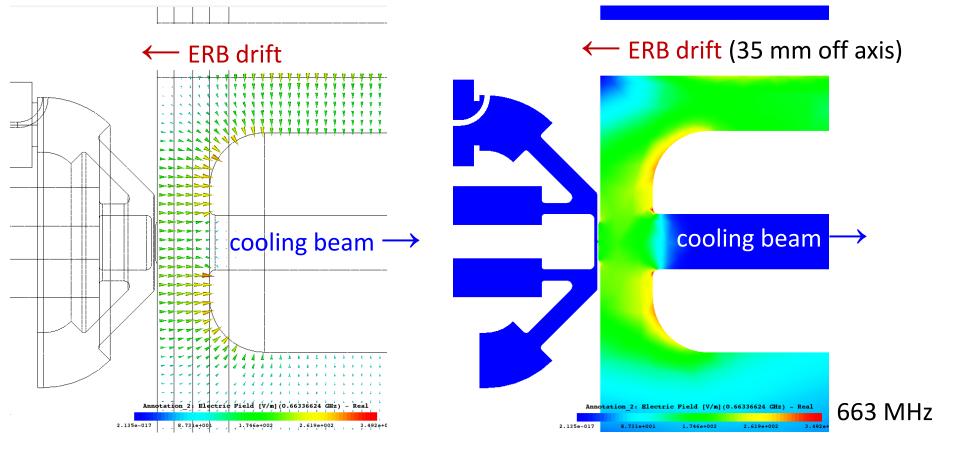
RF Gated Thermionic Electron Source Quarter-wave bunching structure, E-field plots



74.4 MHz

RF Gated Thermionic Electron Source

Quarter-wave bunching structure with ERB drift channel



Dual-Frequency Thermionic Electron Source Modeling and Simulations

Dual-frequency emission gating RF structure

Grid region

